### 捷多邦,专业PCB打样工厂,24小系**NZ4AL**VCH32973 16-BIT BUS TR<mark>ANSCEIVER AND TRANSPARENT D-TYPE</mark> LATCH WITH EIGHT INDEPENDENT BUFFERS

SCES436C-APRIL 2003-REVISED SEPTEMBER 2004

#### **FEATURES**

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- Member of the Texas Instruments Widebus+™
  Family
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

#### DESCRIPTION/ORDERING INFORMATION

This device contains eight independent noninverting buffers and a 16-bit noninverting bus transceiver and D-type latch designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74ALVCH32973 is particularly suitable for demultiplexing an address/data bus into a dedicated address bus and dedicated data bus. The device is used where there is asynchronous bidirectional communication between the A and B data bus, and the address signals are latched and buffered on the Q bus. The control-function implementation minimizes external timing requirements.

This device can be used as one 8-bit buffer, two 8-bit transceivers, and two 8-bit latches or one 8-bit buffer, one 16-bit transceiver, and one 16-bit latch. It allows data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The transceiver output-enable (TOE) input can be used to disable the transceivers so that the A and B buses effectively are isolated.

When the latch-enable (LE) input is high, the Q outputs follow the data (A) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the A inputs. The latch output-enable (LOE) input can be used to place the nine Q outputs in either a normal logic state (high or low logic level) or the high-impedance state. In the high-impedance state, the Q outputs neither drive nor load the bus lines significantly. LOE does not affect internal operations of the latch. Old data can be retained or new data can be entered while the Q outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{\text{LOE}}$  and  $\overline{\text{TOE}}$  should be tied to  $V_{\text{CC}}$  through pullup resistors; the minimum values of the resistors are determined by the current-sinking capability of the drivers.

The eight independent noninverting buffers perform the Boolean function Y = D and are independent of the state of DIR, TOE, LE, and LOE.

The A and B I/Os and D inputs have bus-hold circuitry. Active bus-hold circuitry holds unused or undriven data inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE <sup>(1)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING
40°C to 95°C	LFBGA - GKE	Tono and rool	SN74ALVCH32973KR	ACH973
-40°C to 85°C	LFBGA - ZKE (Pb-free)	Tape and reel	74ALVCH32973ZKER	ACH973

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

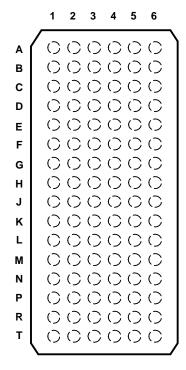
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# GKE OR ZKE PACKAGE (TOP VIEW)



#### **TERMINAL ASSIGNMENTS**

	1	2	3	4	5	6
Α	1A1	D1	1TOE	1DIR	1B1	1Q1
В	1A2	Y1	GND	GND	1B2	1Q2
С	1A3	D2	V <sub>CC</sub>	V <sub>CC</sub>	1B3	1Q3
D	1A4	Y2	GND	GND	1B4	1Q4
Е	1A5	D3	GND	GND	1B5	1Q5
F	1A6	Y3	V <sub>CC</sub>	V <sub>CC</sub>	1B6	1Q6
G	1A7	D4	GND	GND	1B7	1Q7
Н	1A8	Y4	1LE	1LOE	1B8	1Q8
J	2A1	D5	2TOE	2DIR	2B1	2Q1
K	2A2	Y5	GND	GND	2B2	2Q2
L	2A3	D6	V <sub>CC</sub>	V <sub>CC</sub>	2B3	2Q3
М	2A4	Y6	GND	GND	2B4	2Q4
N	2A5	D7	GND	GND	2B5	2Q5
Р	2A6	Y7	V <sub>CC</sub>	V <sub>CC</sub>	2B6	2Q6
R	2A7	D8	GND	GND	2B7	2Q7
Т	2A8	Y8	2LE	2 <del>LOE</del>	2B8	2Q8

#### **FUNCTION TABLES**

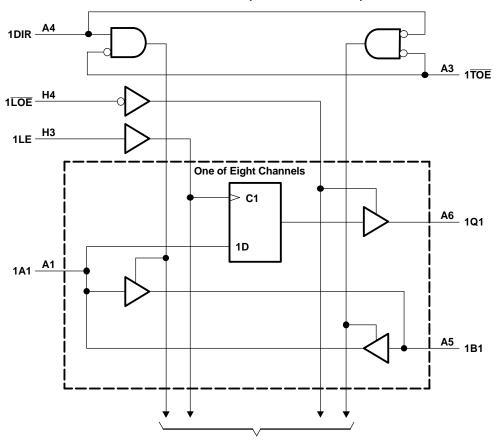
INP	UTS	OPERATION
TOE	DIR	OFERATION
L	L	B data to A bus
L	Н	A data to B bus
Н	Χ	A bus and B bus isolation

	INPUTS	OUTPUT	
LOE	LE	Α	Q
L	Н	Н	Н
L	Н	L	L
L	L	X	$Q_0$
Н	X	X	Z

INPUT D	OUTPUT Y
L	L
Н	Н

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### **LOGIC DIAGRAM (POSITIVE LOGIC)**

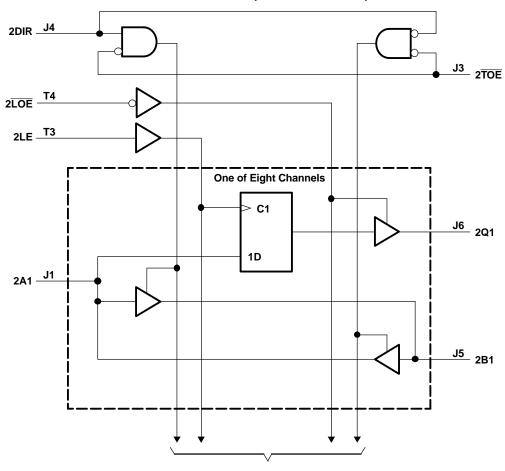


To Seven Other Channels

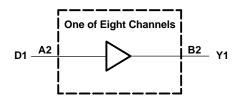


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### **LOGIC DIAGRAM (POSITIVE LOGIC)**



To Seven Other Channels





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### ABSOLUTE MAXIMUM RATINGS(1)

over operating free-air temperature range (unless otherwise noted)

				MIN	MAX	UNIT
$V_{CC}$	V <sub>CC</sub> Supply voltage range			-0.5	4.6	V
VI	Input voltage renge	Except I/O and D input ports (2)		-0.5	4.6	V
	Input voltage range	I/O and D input ports (2)(3)		-0.5	$V_{CC} + 0.5$	V
Vo	Output voltage range <sup>(2)(3)</sup>			-0.5	$V_{CC} + 0.5$	V
I <sub>IK</sub>	Input clamp current	V <sub>I</sub> < 0			-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0			-50	mA
Io	Continuous output current				±50	mA
	Continuous current through each V <sub>C</sub>	c or GND			±100	mA
$\theta_{JA}$	Package thermal impedance (4)	GKE/ZKE package			40	°C/W
T <sub>stg</sub>	Storage temperature range			-65	150	°C

<sup>(1)</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

### RECOMMENDED OPERATING CONDITIONS(1)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage		1.65	3.6	V
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$		
$V_{IH}$	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	2		
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$	
$V_{IL}$	V <sub>IL</sub> Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		0.8	
VI	Input voltage		0	V <sub>CC</sub>	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		V <sub>CC</sub> = 1.65 V		-4	
	High level output ourrent	$V_{CC} = 2.3 \text{ V}$		-12	mA
I <sub>OH</sub>	High-level output current	$V_{CC} = 2.7 \text{ V}$		-12	ША
		$V_{CC} = 3 V$		-24	
		V <sub>CC</sub> = 1.65 V		4	
	Lour lovel output output	$V_{CC} = 2.3 \text{ V}$		12	A
I <sub>OL</sub>	Low-level output current	$V_{CC} = 2.7 \text{ V}$		12	mA
		V <sub>CC</sub> = 3 V		24	
Δt/Δν	Input transition rise or fall rate			10	ns/V
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

<sup>(1)</sup> All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

<sup>(2)</sup> The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

<sup>(3)</sup> This value is limited to 4.6 V maximum.

<sup>(4)</sup> The package thermal impedance is calculated in accordance with JESD 51-7.



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#### **ELECTRICAL CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted)

P	ARAMETER	TEST CO	ONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
		$I_{OH} = -100 \mu A$		1.65 V to 3.6 V	V <sub>CC</sub> - 0.2			
		$I_{OH} = -4 \text{ mA}$		1.65 V	1.2			
		$I_{OH} = -6 \text{ mA}$		2.3 V	2			
$V_{OH}$				2.3 V	1.7			V
		I <sub>OH</sub> = -12 mA		2.7 V	2.2			
				3 V	2.4			
		I <sub>OH</sub> = -24 mA		3 V	2			
		I <sub>OL</sub> = 100 μA		1.65 V to 3.6 V			0.2	
		I <sub>OL</sub> = 4 mA		1.65 V			0.45	
.,		I <sub>OL</sub> = 6 mA		2.3 V			0.4	
$V_{OL}$		1 40 4		2.3 V			0.7	V
		I <sub>OL</sub> = 12 mA		2.7 V			0.4	
		I <sub>OL</sub> = 24 mA		3 V			0.55	
I		$V_I = V_{CC}$ or GND		3.6 V			±5	μΑ
		$V_1 = 0.57 \text{ V}$ $V_1 = 0.7 \text{ V}$		1.65 V	25			μА
I <sub>BHL</sub> (2)	)			2.3 V	45			
		V <sub>I</sub> = 0.8 V	3 V	75				
		V <sub>I</sub> = 1.07 V		1.65 V	-25			
I <sub>BHH</sub> <sup>(3</sup>	i)	V <sub>I</sub> = 1.7 V		2.3 V	-45			μΑ
		V <sub>I</sub> = 2 V		3 V	-75			
				1.95 V	200			
I <sub>BHLO</sub>	(4)	$V_I = 0$ to $V_{CC}$		2.7 V	300			μΑ
				3.6 V	500			
				1.95 V	-200			
I <sub>BHHO</sub>	(5)	$V_I = 0$ to $V_{CC}$		2.7 V	-300			μΑ
				3.6 V	-500			
I <sub>OZ</sub> <sup>(6)</sup>		$V_O = V_{CC}$ or GND		3.6 V			±10	μΑ
I <sub>CC</sub>		$V_I = V_{CC}$ or GND,	I <sub>O</sub> = 0	3.6 V			60	μΑ
$\Delta I_{CC}$		One input at V <sub>CC</sub> - 0.6 V,	Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V			750	μΑ
	Control inputs			0.014		3		_
C <sub>i</sub>	D	$V_I = V_{CC}$ or GND		3.3 V		4		pF
	A ports	V V CND		0.637		4.5		
C <sub>io</sub>	B ports	$V_O = V_{CC}$ or GND		3.3 V	4.5			pF
C <sub>o</sub>	Q	$V_O = V_{CC}$ or GND		3.3 V		3		pF

All typical values are at  $V_{CC}$  = 3.3 V,  $T_A$  = 25°C. The bus-hold circuit can sink at least the minimum low sustaining current at  $V_{IL}$  max.  $I_{BHL}$  should be measured after lowering  $V_{IN}$  to GND and then raising it to  $V_{IL}$  max. The bus-hold circuit can source at least the minimum high sustaining current at  $V_{IH}$  min.  $I_{BHH}$  should be measured after raising  $V_{IN}$ 

to  $V_{CC}$  and then lowering it to  $V_{IH}$  min. An external driver must source at least  $I_{BHLO}$  to switch this node from low to high.

An external driver must sink at least  $I_{BHHO}$  to switch this node from high to low. For I/O ports, the parameter  $I_{OZ}$  includes the input leakage current.



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### **TIMING REQUIREMENTS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

		V <sub>CC</sub> = 1.8 V		$V_{CC} = 1.8 \text{ V} \qquad \begin{array}{c} V_{CC} = 2.5 \text{ V} \\ \pm 0.2 \text{ V} \end{array}$			3.3 V 3 V	UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>w</sub>	Pulse duration, LE high	2		2		2		ns
t <sub>su</sub>	Setup time, data before LE $\downarrow$	0.9		0.9		0.9		ns
t <sub>h</sub>	Hold time, data after LE↓	0.9		0.9		0.9		ns

### **SWITCHING CHARACTERISTICS**

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2 ± 0.2	2.5 V V	V <sub>CC</sub> = 3 ± 0.3	3.3 V V	UNIT
	(INPUT)	(OUTPUT)	TYP	MIN	MAX	MIN	MAX	
	D	Y	2.2	0.5	3.2	0.5	3	
4	A	Q	2.2	0.5	3.2	0.5	3	20
$t_{pd}$	LE	Q	2.8	0.5	3.3	0.5	3	ns
	A or B B o	B or A	2.2	0.5	3.2	0.5	3	
	LOE	Q	2.9	0.7	4.9	0.7	4.7	
t <sub>en</sub>	TOE	A or P	3	0.7	4.6	0.7	4.4	ns
	DIR	A or B	3.4	0.7	4.9	0.7	4.7	
	LOE	Q	2.8	0.5	4.3	0.5	4.1	
t <sub>dis</sub>	t <sub>dis</sub> TOE	3.2	0.5	4.3	0.5	4.1	ns	
	DIR	A or B	3.4	0.5	4.9	0.5	4.7	



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### OPERATING CHARACTERISTICS(1)

 $T_A = 25^{\circ}C$ 

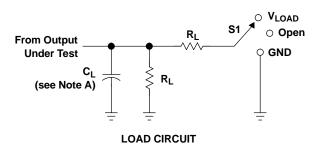
	PARAMETE	:R	TEST CONDITIONS	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	UNIT
		A outputs enabled, Q outputs disabled, one A output switching	$\begin{aligned} &\text{One } f_A = 10 \text{ MHz}, \\ &\text{One } f_B = 10 \text{ MHz}, \\ &\overline{\text{TOE}} = \text{GND}, \\ &\text{LOE} = \text{V}_{\text{CC}}, \\ &\text{DIR} = \text{GND}, \\ &\text{C}_L = 0 \text{ pF} \end{aligned}$	12	14	19	
C <sub>pd</sub> <sup>(2)</sup> Power dissipation	B outputs enabled, Q outputs disabled, one B output switching	$\label{eq:control_approx} \begin{split} &\text{One } f_A = 10 \text{ MHz}, \\ &\text{One } f_B = 10 \text{ MHz}, \\ &\text{TOE} = GND, \\ &\text{LOE} = V_{CC}, \\ &\text{DIR} = GND, \\ &C_L = 0 \text{ pF} \end{split}$	12	14	21	pF	
(each output)	capacitance	Q outputs enabled, A and B I/Os isolated, one Q output switching	$\begin{aligned} &\text{One } f_A = 10 \text{ MHz}, \\ &\text{One } f_{LE} = 20 \text{ MHz}, \\ &\text{One } f_Q = 10 \text{ MHz}, \\ &\overline{\text{TOE}} = V_{CC}, \\ &\overline{\text{LOE}} = GND, \\ &C_L = 0 \text{ pF} \end{aligned}$	11	13	19	
		One Y output switching, A and B I/Os isolated, Q outputs disabled	$\label{eq:fd} \begin{array}{l} \text{One } f_D = 10 \text{ MHz},\\ \text{One } f_Y = 10 \text{ MHz},\\ \hline \text{TOE} = V_{CC},\\ \hline \text{LOE} = V_{CC},\\ C_L = 0 \text{ pF} \end{array}$	7	8	12	
C <sub>pd</sub> (Z)	Power dissipation capacitance	A and B I/Os isolated, Q outputs disabled, one LE and one A data input switching	$\label{eq:continuous_section} \begin{split} &\text{One } f_A = 10 \text{ MHz}, \\ &\text{One } f_{LE} = 20 \text{ MHz}, \\ &f_Q \text{ not switching}, \\ &\overline{\text{TOE}} = V_{CC}, \\ &\overline{\text{LOE}} = V_{CC}, \\ &C_L = 0 \text{ pF} \end{split}$	4	5	11	pF
C <sub>pd</sub> <sup>(3)</sup> (each LE)	Power dissipation capacitance	A and B I/Os isolated, Q outputs disabled, one LE input switching	$\begin{aligned} &f_A \text{ not switching,} \\ &\text{One } f_{LE} = 20 \text{ MHz,} \\ &f_Q \text{ not switching,} \\ &\overline{\text{TOE}} = V_{CC}, \\ &\overline{\text{LOE}} = V_{CC}, \\ &C_L = 0 \text{ pF} \end{aligned}$	6	7	9	pF

Total device  $C_{pd}$  for multiple (m) outputs switching and (n) LE inputs switching = [m \*  $C_{pd}$  (each output)] + [n \*  $C_{pd}$  (each LE)]  $C_{pd}$  (each output) is the  $C_{pd}$  for each data bit (input and output circuitry) when it operates at 10 MHz (Note: The LE is operating at 20 MHz in this test, but its  $I_{CC}$  component has been subtracted).  $C_{pd}$  (each LE) is the  $C_{pd}$  for the clock circuitry only when it operates at 20 MHz.



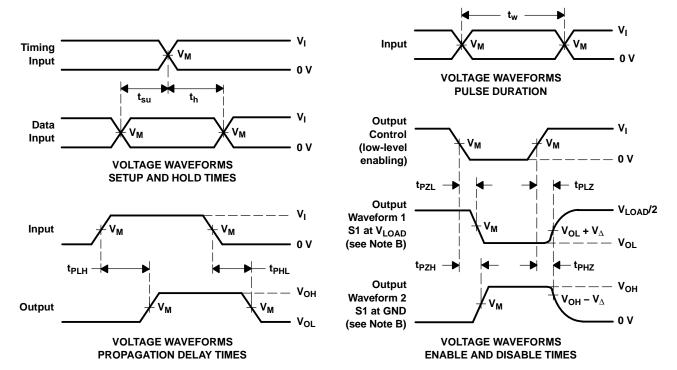
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#### PARAMETER MEASUREMENT INFORMATION



TEST	S1
t <sub>pd</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	$V_{LOAD}$
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

v	INPUT		V	V		В	V
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	V <sub>M</sub>	V <sub>LOAD</sub>	CL	R <sub>L</sub>	$V_{\Delta}$
1.8 V	V <sub>CC</sub>	≤ <b>2</b> ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	<b>1 k</b> Ω	0.15 V
2.5 V $\pm$ 0.2 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	2×V <sub>CC</sub>	30 pF	500 Ω	0.15 V
3.3 V $\pm$ 0.3 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z<sub>O</sub> = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t<sub>PLZ</sub> and t<sub>PHZ</sub> are the same as t<sub>dis</sub>.
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 1. Load Circuit and Voltage Waveforms



#### PACKAGE OPTION ADDENDUM

30-Mar-2005

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
74ALVCH32973ZKER	ACTIVE	LFBGA	ZKE	96	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-3-250C-168 HR
SN74ALVCH32973KR	ACTIVE	LFBGA	GKE	96	1000	TBD	SNPB	Level-3-220C-168 HR

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check <a href="http://www.ti.com/productcontent">http://www.ti.com/productcontent</a> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

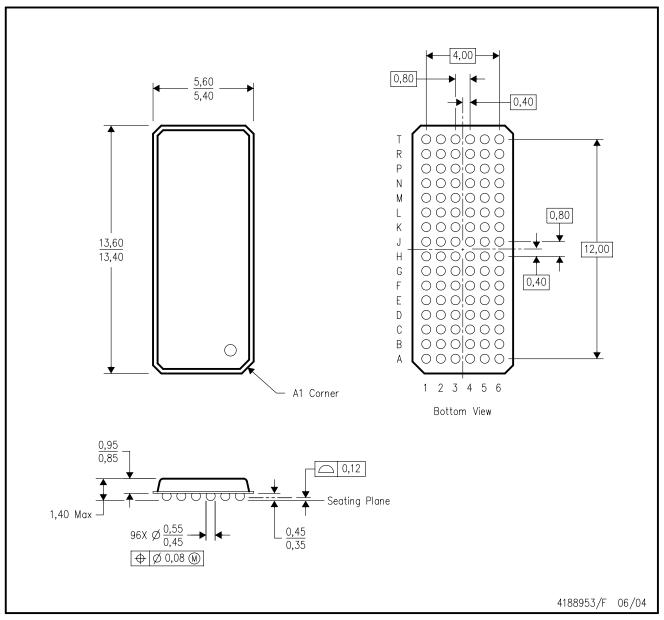
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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# GKE (R-PBGA-N96)

# PLASTIC BALL GRID ARRAY



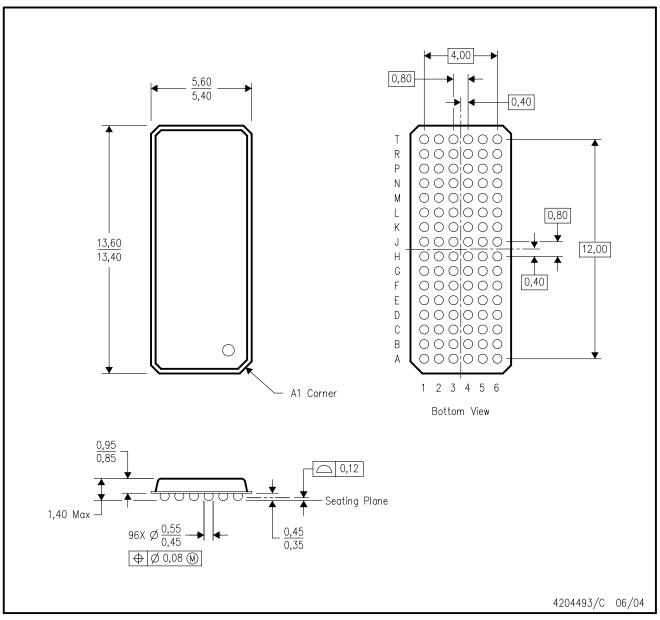
NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is tin-lead (SnPb). Refer to the 96 ZKE package (drawing 4204493) for lead-free.



# ZKE (R-PBGA-N96)

# PLASTIC BALL GRID ARRAY



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-205 variation CC.
- D. This package is lead-free. Refer to the 96 GKE package (drawing 4188953) for tin-lead (SnPb).



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Mailing Address: Texas Instruments

Post Office Box 655303 Dallas, Texas 75265